Current-Shunt Monitor, Voltage Output, Bi-Directional Zero-Drift

The NCS210, NCV210, and NCS211 are voltage output current shunt monitors that can measure voltage across shunts at common-mode voltages from -0.3 V to 26 V, independent of supply voltage. Two fixed gains are available: 200 V/V, or 500 V/V. The low offset of the zero-drift architecture enables current sensing with maximum drops across the shunt as low as 10 mV full-scale.

The devices can operate from a single +2.7 V to +26 V power supply, drawing a maximum of 100 μ A of supply current. All versions are specified over the extended operating temperature range (-40°C to +125°C). Available in SC-70 and thin UQFN space-saving packages.

Features

- Wide Common–Mode Input Range –0.3 V to 26 V
- Supply Voltage Range from 2.7 V to 26 V
- Low Offset Voltage ±60 µV Max
- Low Offset Drift (0.1 μ V/°C)
- Low Gain Error (Max 1%)
- Rail-to-Rail Input and Output Capability
- Low Current Consumption (typ 65 μA, 100 μA max)
- NCV Prefix for Automotive and Other Applications Requiring Unique Site Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

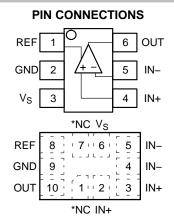
- Current Sensing (High–Side/Low–Side)
- Automotive
- Telecom
- Sensors



ON Semiconductor®

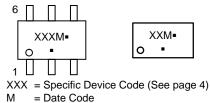
www.onsemi.com

-	
SC70-6	UQFN10
SQ SUFFIX	MU SUFFIX
CASE 419B	CASE 488AT



*NC denotes no internal connection. These pins can be left floating or connected to any voltage between Vs and GND.

MARKING DIAGRAMS



= Pb-Free Package

(Note: Microdot may be in either location)

Product	Gain	R3-R4	R1-R2
NCS210	200	5 kΩ	1 MΩ
NCV210	200	$5 \ k\Omega$	1 MΩ
NCS211	500	2 kΩ	1 MΩ

$$V_{OUT} = (I_{LOAD} \times R_{SHUNT})GAIN + V_{REF}$$

ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 4 of this data sheet.

This document contains information on some products that are still under development. ON Semiconductor reserves the right to change or discontinue these products without notice.

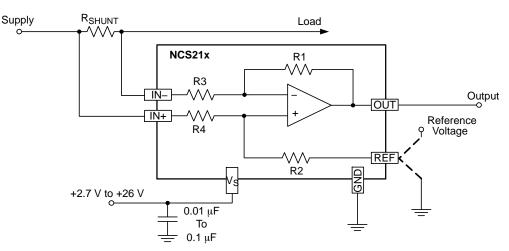


Figure 1. Application Schematic

Table 1. MAXIMUM RATINGS

	Rating	Symbol	Value	Unit	
Supply Voltage (Note 1)		NCS21x NCV21x	V _S	+26 +28	V
Analog Inputs	Differential (V _{IN+})–(V _{IN-})		V_{IN+}, V_{IN-}	-26 to +26	V
	Common–Mode (Note 2)	NCS21x NCV21x		GND-0.3 to +26 GND-0.3 to +28	
REF Input			V _{REF}	GND-0.3 to (V _s) +0.3	V
Output (Note 2)			V _{OUT}	GND–0.3 to (V _s) +0.3	V
Input Current into Any Pin (Note	2)			5	mA
Maximum Junction Temperature			T _{J(max)}	+150	°C
Storage Temperature Range			TSTG	-65 to +150	°C
ESD Capability, Human Body Model (Note 3)				±3000	V
ESD Capability, Machine Model (Note 3)			MM	±100	V
Charged Device Model (Note 3)			CDM	±1000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Refer to ELECTRICAL CHARACTERISTICS, RECOMMENDED OPERATING RANGES and/or APPLICATION INFORMATION for safe operating parameters.

2. Input voltage at any pin may exceed the voltage shown if current at that pin is limited to 5 mA.

3. This device series incorporates ESD protection and is tested by the following methods

ESD Human Body Model tested per AEC–Q100–002 (EIA/JESD22–A114) ESD Machine Model tested per AEC–Q100–003 (EIA/JESD22–A115) ESD Charged Device Model tested per AEC–Q100–011.

Latchup Current Maximum Rating: 50 mA per JEDEC standard: JESD78

Table 2. THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Characteristics (Note 4) Thermal Resistance, Junction-to-Air (Note 5) UQFN10	R _{θJA}	250 300	°C/W

4. Refer to ELECTRICAL CHARACTERISTICS, RECOMMENDED OPERATING RANGES and/or APPLICATION INFORMATION for safe operating parameters.

5. Values based on copper area of 645 mm² (or 1 in²) of 1 oz copper thickness and FR4 PCB substrate.

Table 3. RECOMMENDED OPERATING RANGES

Rating	Symbol	Min	Max	Unit
Supply Voltage	VS	2.7	26	V
Ambient Temperature	T _A	-40	125	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

Table 4. ELECTRICAL CHARACTERISTICSBoldface limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to 125°C, guaranteed by characterization and/or design.At $T_A = +25^{\circ}C$, $V_{SENSE} = V_{IN+} - V_{IN-}$.NCS210, NCV210: $V_S = +5 V$, $V_{IN+} = 12 V$, and $V_{REF} = V_S/2$, unless otherwise noted.NCS211: $V_S = +12 V$, $V_{IN+} = 12 V$, and $V_{REF} = V_S/2$, unless otherwise noted.

_		0	, 111	, and incli	0					
	Parameter		Test Conditions	Symbol	Min	Тур	Max	Unit		
-	GAIN									

NCS210, NCV210 NCS211			G		200 500		V/V
Gain Error	NCS210, NCS211	V _{SENSE} = -5 mV to 5 mV	G _e		±0.2	±1	%
	NCV210	$V_{SENSE} = -5 \text{ mV to } 5 \text{ mV}$	G _e		±0.2	±1.5	%
Gain Error vs. Temp.	NCS210, NCS211	$T_A = -10^{\circ}C$ to $125^{\circ}C$	č		7	14	ppm/°C
	NCV210	$T_{A} = -40^{\circ}C \text{ to } 125^{\circ}C$			7	70	ppm/°C
Nonlinearity Error		$V_{SENSE} = -5 \text{ mV to } 5 \text{ mV}$			±0.01	_	%
Maximum Capacitive	Load	No sustained oscillation			1		nF
VOLTAGE OFFSET			I		I	1	
Offset Voltage (RTI Note 6)	NCS210, NCS211	V _{SENSE} = 0 mV	V _{OS}		±0.55	±60	μV
	NCV210				±0.55	±90	μV
Offset Drift	NCS210, NCS211		δV/δΤ		0.1	0.6	μV/°C
	NCV210		δV/δΤ		0.1	1.0	μV/°C
INPUT	•					1	
Input Bias Current		V _{SENSE} = 0 mV	I _{IB}			60	μA
Common-Mode Input	Voltage Range		V _{CM}	-0.3		26	V
Common–Mode Rejection Ratio	NCS210, NCS211	V _S = 5 V, V _{IN+} = 2 V to +26 V, V _{SENSE} = 0 mV	CMRR	103	115		dB
		$V_S = 3.3 \text{ V}, V_{IN+} = 3 \text{ V} \text{ to } +26 \text{ V},$ $V_{SENSE} = 0 \text{ mV}$		103	115		dB
		$V_{S} = 3.3 \text{ V}, V_{IN+} = 0 \text{ V} \text{ to } +26 \text{ V},$ $V_{SENSE} = 0 \text{ mV} (T_{A} = -10^{\circ}\text{C to } 85^{\circ}\text{C})$		103	120		dB
Common–Mode Rejection Ratio	NCV210	V _S = 5 V, V _{IN+} = 2 V to +26 V, V _{SENSE} = 0 mV	CMRR	100	115		dB
		$V_S = 3.3 \text{ V}, V_{IN+} = 3 \text{ V} \text{ to } +26 \text{ V},$ $V_{SENSE} = 0 \text{ mV}$		100	115		dB
OUTPUT							
Output Voltage Low		Referenced from GND R _L = 10 kΩ to Ground	V _{OL}		5	50	mV
Output Voltage High		Referenced from V _S R_L = 10 k Ω to Ground	V _{OH}		0.05	0.2	V
DYNAMIC PERFORM	ANCE						-
Bandwidth (f _{-3dB})		C_{LOAD} = 10 pF, NCS210, NCV210 C_{LOAD} = 10 pF, NCS211	BW		40 25		kHz
Slew Rate			SR		0.4		V/μs
NOISE							-
Spectral Density, 1 kH	z (RTI Note 6)		en		35		nV/√H
POWER SUPPLY				1	1		
Operating Voltage Range		V _{SENSE} = 0 mV	Vs	2.7		26	V
Quiescent Current		V _{SENSE} = 0 mV	I _{DD}		65	100	μA
Quiescent Current ove	er Temperature	V _{SENSE} = 0 mV				115	μΑ
Power Supply Rejection	on Ratio	V_S = +2.7 V to +26 V, V_{IN+} =18 V, V_{SENSE} = 0 mV	PSRR		±0.1	±10	μV/V

6. RTI = referenced-to-input.

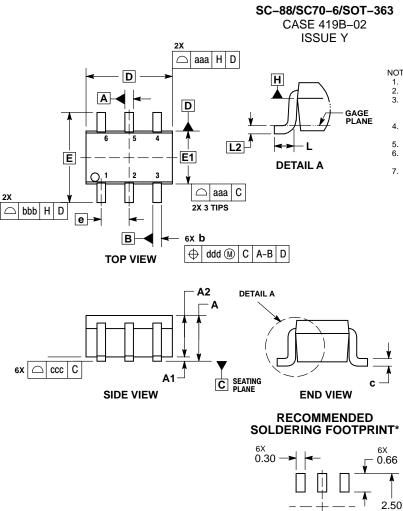
ORDERING INFORMATION

Device	Gain	Marking	Package	Shipping [†]
NCS210SQT2G	200	AAP		
NCS211SQT2G	500	AAM	SC70–6 (Pb–Free)	3000 / Tape and Reel
NCV210SQT2G *	200	VAP	(
NCS210MUTAG (In Development)**	200	TBD	UQFN10 (Pb–Free)	3000 / Tape and Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D

*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable. ** Contact local sales office for availability.

PACKAGE DIMENSIONS



NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRU-SIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER END. DIMENSIONS D AND E1 AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY AND DATUM H. DATUMS A AND B ARE DETERMINED AT DATUM H. DIMENSIONS D AND c APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.08 AND 0.15 FROM THE TIP. DIMENSION & DORS NOT INCLUDE DAMBAR PROTRUISION
- 5.
- DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 TOTAL IN EXCESS OF DIMENSION 5 AT MAXIMUM MATERIAL CONDI-TION. THE DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OF THE FOOT.

	MIL	LIMETE	RS		INCHES	3	
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α			1.10			0.043	
A1	0.00		0.10	0.000		0.004	
A2	0.70	0.90	1.00	0.027	0.035	0.039	
b	0.15	0.20	0.25	0.006	0.008	0.010	
С	0.08	0.15	0.22	0.003	0.006	0.009	
D	1.80	2.00	2.20	0.070	0.078	0.086	
Е	2.00	2.10	2.20	0.078	0.082	0.086	
E1	1.15	1.25	1.35	0.045	0.049	0.053	
e		0.65 BS	С	0.026 BSC			
Г	0.26	0.36	0.46	0.010	0.014	0.018	
L2		0.15 BS	C		0.006 BS	SC	
aaa		0.15		0.006			
bbb		0.30		0.012			
CCC		0.10		0.004			
ddd		0.10			0.004		

DIMENSIONS: MILLIMETERS

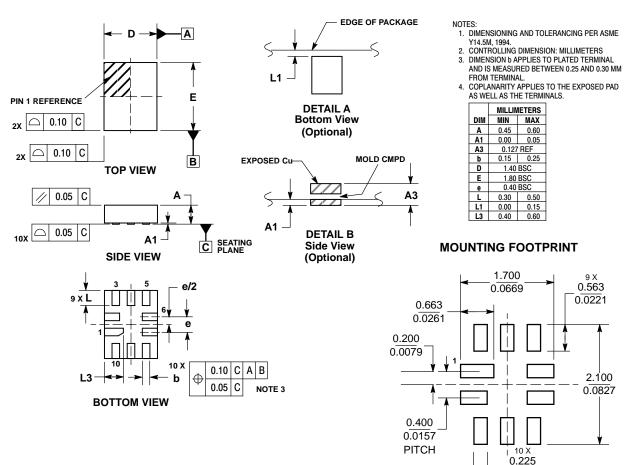
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

0.65 PITCH

PACKAGE DIMENSIONS

UQFN10 1.4x1.8, 0.4P CASE 488AT





ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns me rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor roducts, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor dates sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights or the rights of others. ON Semiconductor and is officiens, employees or use ON Semiconductor products have any existing application or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, d

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81–3–5817–1050 ON Semiconductor Website: www.onsemi.com

0.0089

SCALE 20:1 (minutes

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Current Sense Amplifiers category:

Click to view products by ON Semiconductor manufacturer:

Other Similar products are found below :

MCP6C02T-050H/Q8B_TSC210ICT_INA212BIDCKR_MAX4372HEBT+T_NTE955M_INA199C3DCKT_LTC6102IDD#PBF FAN4010IL6X-F113_LT6100IDD#PBF_LT1217CN8#PBF_INA212CIDCKR_LMP8480ASQDGKRQ1_INA212CIRSWT_ LMP8481AHQDGKRQ1_LT6108HDCB-1#TRMPBF_INA211CIRSWT_LT6108AHMS8-1#PBF_INA214CIRSWR_LT1620CMS8#PBF INA215CIDCKR_LTC6101HVBCS5#TRMPBF_LT6106HS5#PBF_NTE1609_NTE926_NTE955MC_NTE955S_NTE955SM_NTE978 NTE978C_NTE978SM_AD8211YRJZ-R2_AD8213WHRMZ_AD8214ARMZ_AD8214ARMZ-R7_AD8219BRMZ_AD8290ACPZ-R2 AD8290ACPZ-R7_AD22057RZ_AD8215YRZ_AD8210YRZ_AD22057RZ-RL_AD8210YRZ-REEL7_AD8215WYRZ_AD8210WYRZ-R7 ADM4073FWRJZ-REEL7_LT1999HMS8-50F#WPBF_LT1999HMS8-10F#WPBF_LTC6102HVIMS8#PBF_LTC6101AIMS8#PBF LTC6102CMS8-1#PBF